

# SB100-09K

Schottky Barrier Diode (Twin Type - Cathode Common)

# 90V, 10A Rectifier

### **Applications**

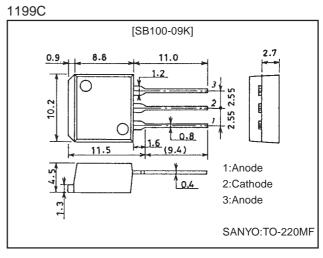
• High frequency rectification (switching regulators, converters, choppers).

### **Features**

- · Low forward voltage ( $V_F$  max=0.85V).
- $\cdot$  Fast reverse recovery time (trr max=45ns).
- · Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.

## **Package Dimensions**

unit:mm



## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

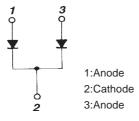
| Parameter                                | Symbol           | Conditions                    | Ratings     | Unit |
|--|------------------|-------------------------------|-------------|------|
| Repetitive Peak Reverse Voltage          | V <sub>RRM</sub> |                               | 90          | V    |
| Nonrepetitive Peak Reverse Surge Voltage | VRSM             |                               | 95          | V    |
| Average Output Current                   | IO               | 50Hz, resistive load, Tc=92°C | 10          | Α    |
| Surge Forward Current                    | IFSM             | 50Hz sine wave, 1 cycle       | 80          | A    |
| Junction Temperature                     | Tj               |                               | -55 to +125 | °C   |
| Storage Temperature                      | Tstg             |                               | -55 to +125 | °C   |

### **Electrical Characteristics at Ta = 25°C**

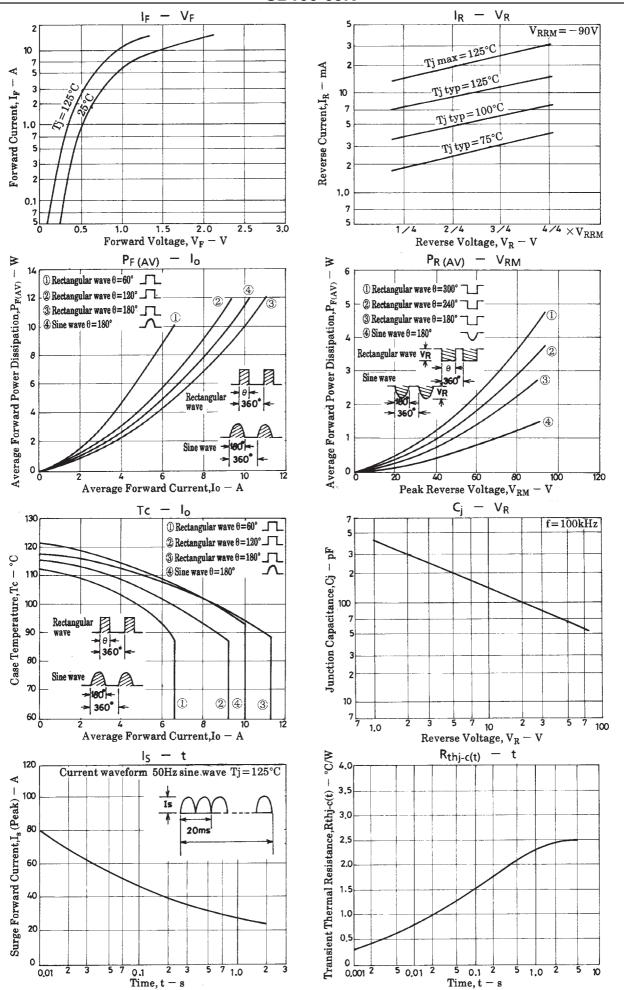
| Parameter             | Symbol         | Conditons  | Ratings |     |      | Unit |
|-----------------------|----------------|--|---------|-----|------|------|
|                       |                |  | min     | typ | max  | Unit |
| Reverse Voltage       | VR             | I <sub>R</sub> =2mA, Tj=25°C, *                              | 90      |     |      | V    |
| Forward Voltage       | ٧ <sub>F</sub> | I <sub>F</sub> =4A, Tj=25°C, *                               |         |     | 0.85 | V    |
| Reverse Current       | IR             | V <sub>R</sub> =45V, Tj=25°C, *                              |         |     | 0.4  | mA   |
| Reverse Recovery Time | trr            | I <sub>F</sub> =2mA, Tj=25°C, *, -dI <sub>F</sub> /dt=10A/μs |         |     | 45   | ns   |
| Thermal Resistance    | Rthj-c         | Junction-Case:Smoothed DC                                    |         |     | 2.5  | °C/W |

Note \*: Value per element

### **Electrical Connection**



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